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FGAF40N60UF 600 V PT IGBT

General Description

Fairchild's UF series of IGBTs provide low conduction and switching losses. The UF series is designed for applications such as general inverters and PFC where high speed switching is a required feature.

Features

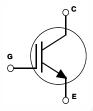
- · High Speed Switching
- Low Saturation Voltage: $V_{CE(sat)} = 2.3 \text{ V} @ I_C = 20 \text{ A}$
- High Input Impedance

Applications

General Inverter, PFC



GCE



Absolute Maximum Ratings T_C = 25°C unless otherwise noted

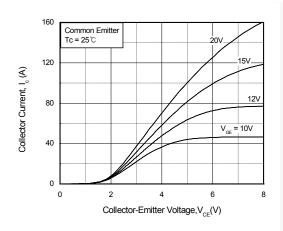
Symbol	Description		Ratings	Unit
V_{CES}	Collector-Emitter Voltage		600	V
V _{GES}	Gate-Emitter Voltage		± 20	V
. \	Collector Current	@ T _C = 25°C	40	Α
I _C	Collector Current	@ T _C = 100°C	20	Α
I _{CM (1)}	Pulsed Collector Current		160	Α
P _D	Maximum Power Dissipation	@ T _C = 25°C	100	W
	Maximum Power Dissipation	@ T _C = 100°C	40	W
T _J	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C
T _L	Maximum Lead Temp. for Soldering Purposes, 1/8" from Case for 5 Seconds		300	°C

Notes: (1) Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction-to-Case		1.2	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	-	40	°C/W

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Cha	racteristics					
BV _{CES}	Collector-Emitter Breakdown Voltage	$V_{GE} = 0 \text{ V, } I_{C} = 250 \text{ uA}$	600			V
$\Delta B_{VCES}/$ ΔT_J	Temperature Coefficient of Breakdown Voltage	V _{GE} = 0 V, I _C = 1 mA		0.6		V/°C
I _{CES}	Collector Cut-Off Current	V _{CE} = V _{CES} , V _{GE} = 0 V			250	uA
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0 V$			± 100	nA
On Cha	racteristics					
V _{GE(th)}	G-E Threshold Voltage	I_C = 20 mA, V_{CE} = V_{GE}	3.5	5.1	6.5	V
	Collector to Emitter	I _C = 20 A, V _{GE} = 15 V		2.3	3.0	V
V _{CE(sat)}	Saturation Voltage	I _C = 40 A, V _{GE} = 15 V		3.1		V
	- Ol and at an latte	, <u> </u>			1 1	
	c Characteristics					
C _{ies}	Input Capacitance	$V_{CE} = 30 \text{ V} V_{GE} = 0 \text{ V},$		1075		pF
C _{oes}	Output Capacitance	f = 1 MHz		170		pF
C _{res}	Reverse Transfer Capacitance			50		pF
Switchi	ng Characteristics					
t _{d(on)}	Turn-On Delay Time			15		ns
t _r	Rise Time			30		ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 300 \text{ V}, I_{C} = 20 \text{ A},$		65	130	ns
t _f	Fall Time	$R_G = 10 \Omega, V_{GE} = 15 V,$		35	100	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 25°C		470		uJ
E _{off}	Turn-Off Switching Loss			130		
_						uJ
E _{ts}	Total Switching Loss			600	1000	uJ uJ
	Total Switching Loss Turn-On Delay Time			600 30	1000	
t _{d(on)}	5				1000 	uJ
t _{d(on)} t _r	Turn-On Delay Time	V _{CC} = 300 V, I _C = 20 A,		30	1000 200	uJ ns
t _{d(on)} t _r t _{d(off)}	Turn-On Delay Time Rise Time	$V_{CC} = 300 \text{ V, } I_{C} = 20 \text{ A,}$ $R_{G} = 10 \Omega, V_{GE} = 15 \text{ V,}$		30 37		uJ ns ns
$t_{d(on)}$ t_r $t_{d(off)}$	Turn-On Delay Time Rise Time Turn-Off Delay Time			30 37 110	 200	uJ ns ns ns
$t_{d(on)}$ t_r $t_{d(off)}$ t_f E_{on}	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time	$R_G = 10 \Omega, V_{GE} = 15 V,$	 	30 37 110 80	 200 250	uJ ns ns ns
t _{d(on)} t _r t _{d(off)} t _f E _{on}	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss	$R_G = 10 \Omega, V_{GE} = 15 V,$	 	30 37 110 80 500	 200 250	ns ns ns ns uJ
$t_{d(on)}$ t_r $t_{d(off)}$ t_f E_{on} E_{off} E_{ts}	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss	$R_G = 10 \Omega$, $V_{GE} = 15 V$, Inductive Load, $T_C = 125^{\circ}C$	 	30 37 110 80 500 310	200 250 	ns ns ns ns ns uJ uJ
$\begin{array}{c} t_{d(on)} \\ t_r \\ t_{d(off)} \\ t_f \\ E_{on} \\ E_{off} \\ E_{ts} \\ Q_g \end{array}$	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss Total Switching Loss	$R_G = 10 \Omega$, $V_{GE} = 15 V$, Inductive Load, $T_C = 125^{\circ}C$ $V_{CE} = 300 V$, $I_C = 20 A$,	 	30 37 110 80 500 310 810	200 250 1200	ns ns ns ns ns uJ uJ
Ets td(on) tr td(off) tf Eon Ets Qg Qge Qgc	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss Total Switching Loss Total Gate Charge	$R_G = 10 \Omega$, $V_{GE} = 15 V$, Inductive Load, $T_C = 125^{\circ}C$	 	30 37 110 80 500 310 810 77	 200 250 1200 150	ns ns ns ns uJ uJ uJ



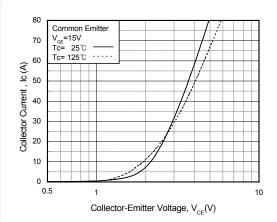
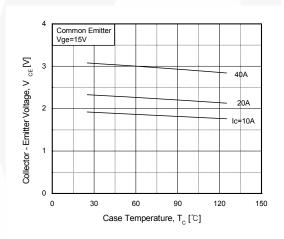


Fig 1. Typical Output Characteristics

Fig 2. Typical Saturation Voltage Characteristics



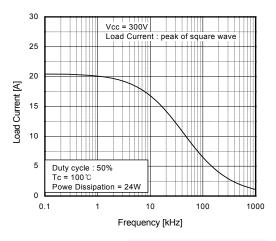
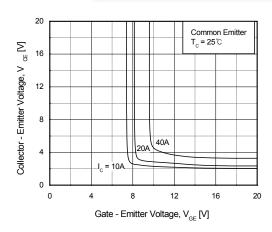


Fig 3. Saturation Voltage vs.

Case Temperature at Variant Current Level

Fig 4. Load Current vs. Frequency



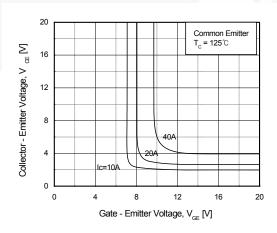
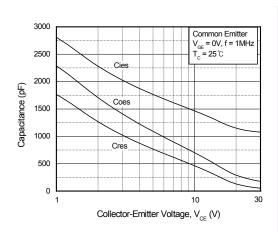


Fig 5. Saturation Voltage vs. V_{GE}

Fig 6. Saturation Voltage vs. V_{GE}



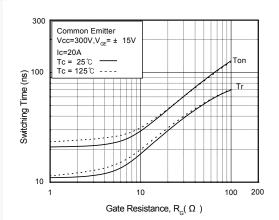
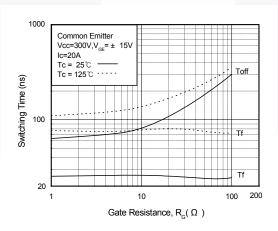


Fig 7. Capacitance Characteristics

Fig 8. Turn-On Characteristics vs.
Gate Resistance



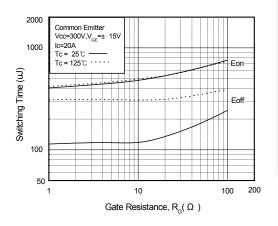
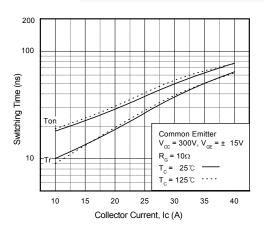


Fig 9. Turn-Off Characteristics vs.
Gate Resistance

Fig 10. Switching Loss vs. Gate Resistance



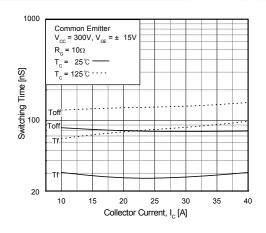
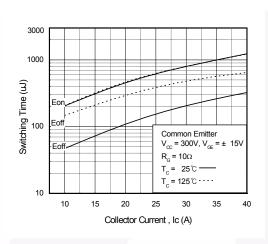


Fig 11. Turn-On Characteristics vs. Collector Current

Fig 12. Turn-Off Characteristics vs. Collector Current



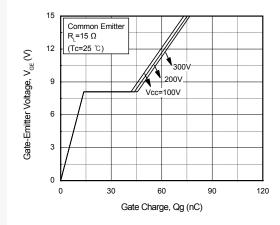
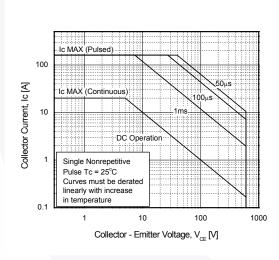


Fig 13. Switching Loss vs. Collector Current

Fig 14. Gate Charge Characteristics



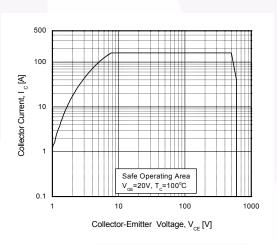


Fig 15. SOA Characteristics

Fig 16. Turn-Off SOA Characteristics

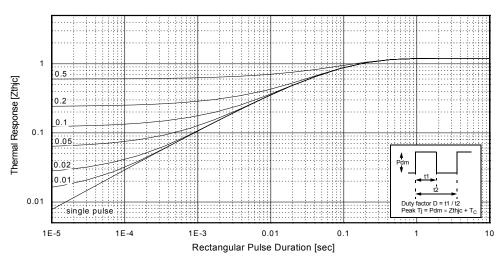


Fig 17. Transient Thermal Impedance of IGBT

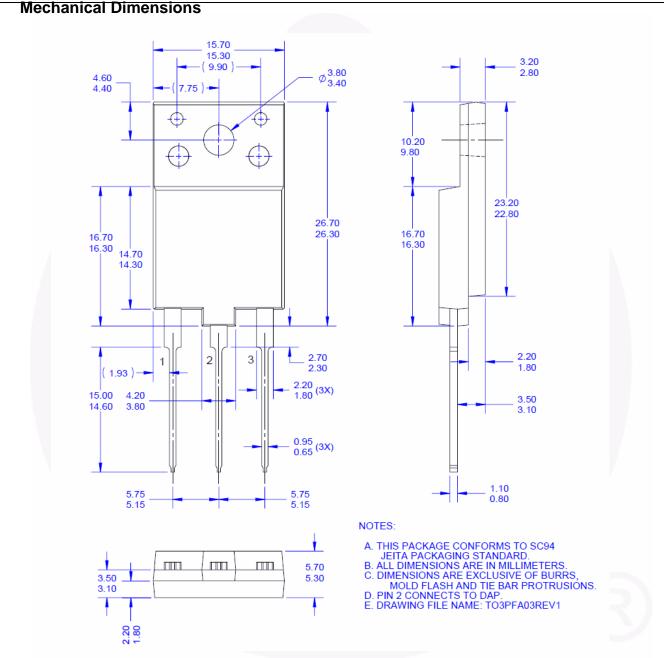


Figure 18. TO3PF,MOLDED,3LD,FULLPACK (AG)

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